

How to select (group) sensors for a single tower?

(gain, PDE, temperature dependence, dark noise rate, etc.)

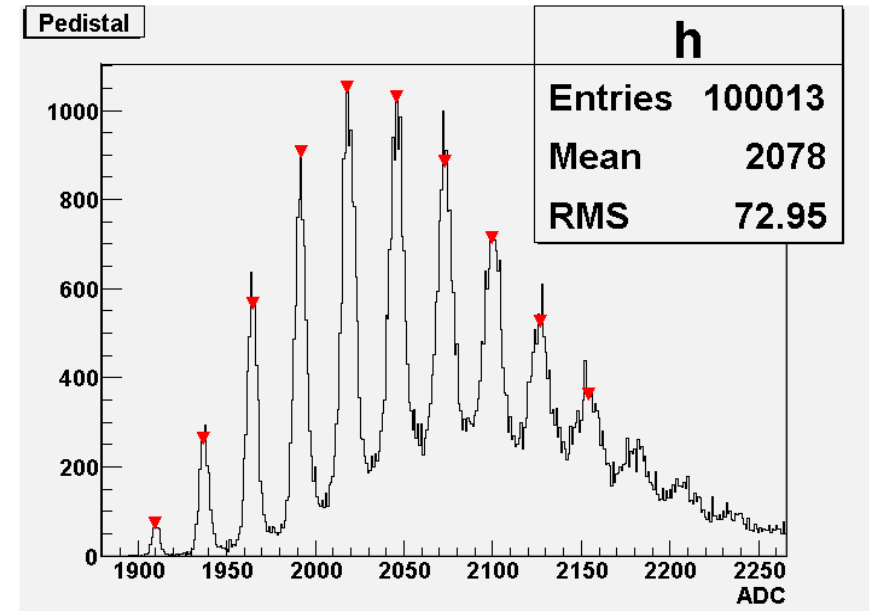
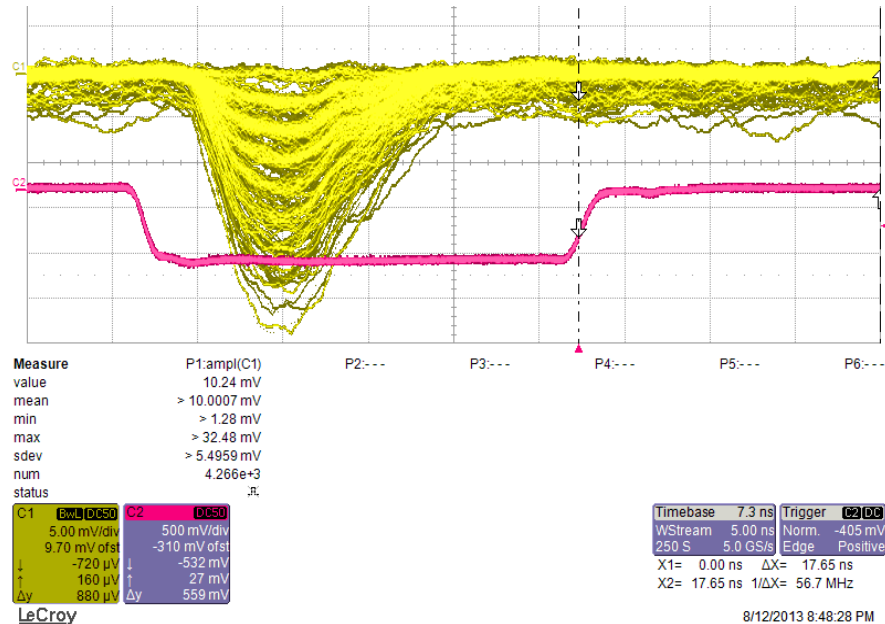
(gain, and T dependence adjusted/compensated at FEE)

b) PDE, what actually do we measure with the test setup?

c) Choice of optimal bias voltage?

08/15/2013

O.Tsai (UCLA)



GLUEX sensors Our Sensors mass testing

Gate

~120ns

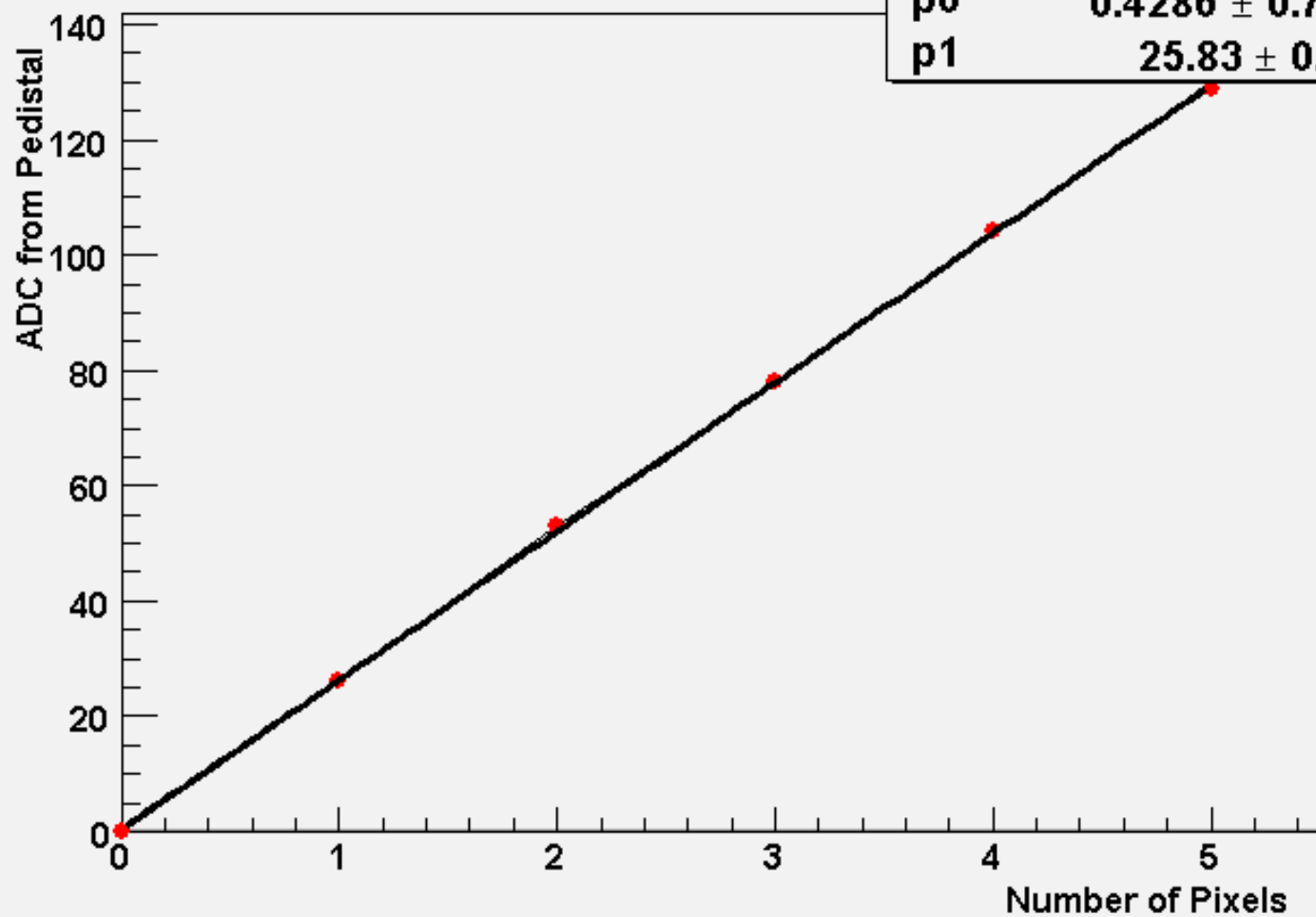
20ns

Breakdown Voltage ~70.4 V

~ 69.3V

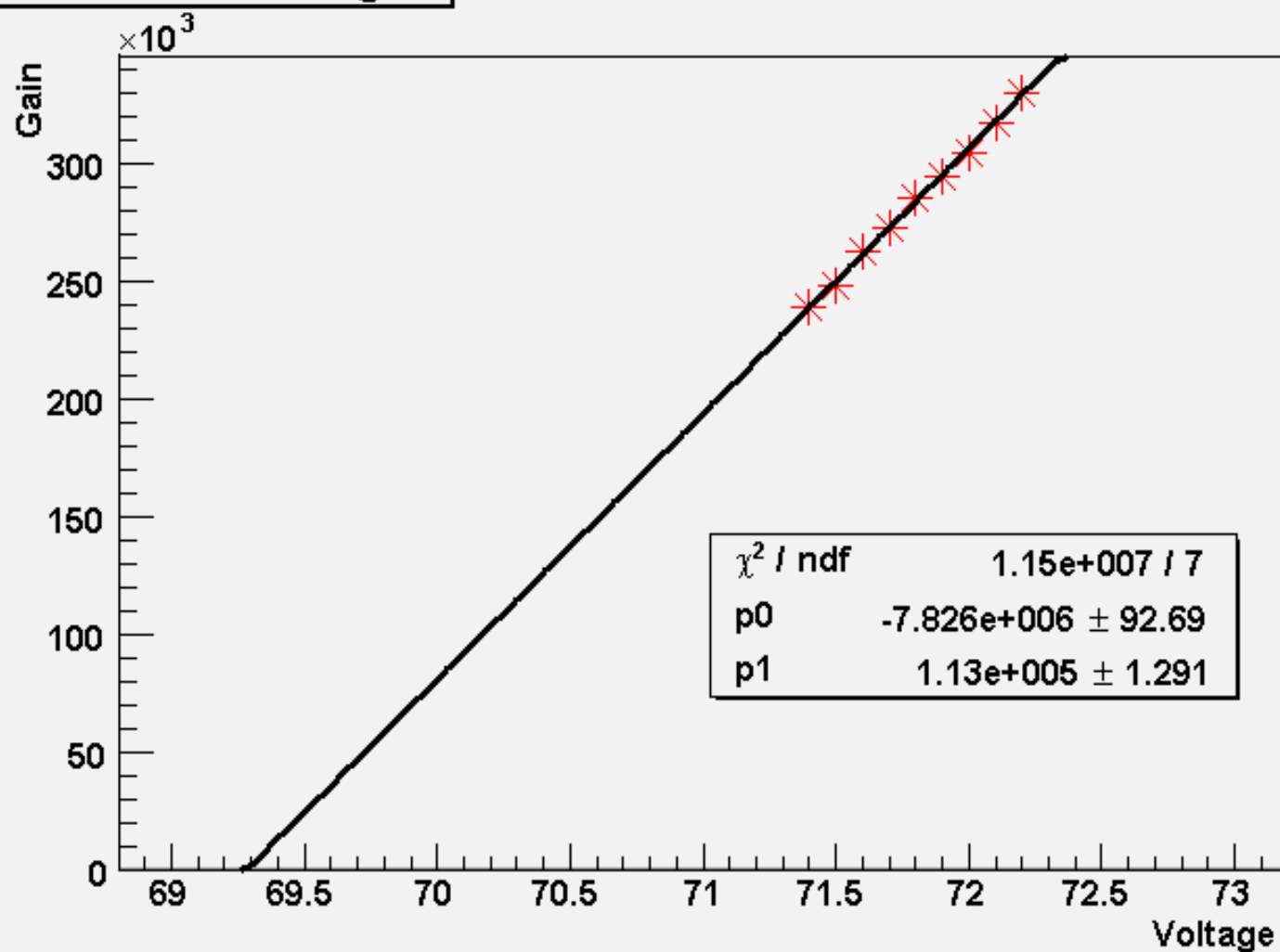
Gain $5 \cdot 10^5$ at 1V above breakdown Same at 3V above breakdown

Pixel Position vs ADC

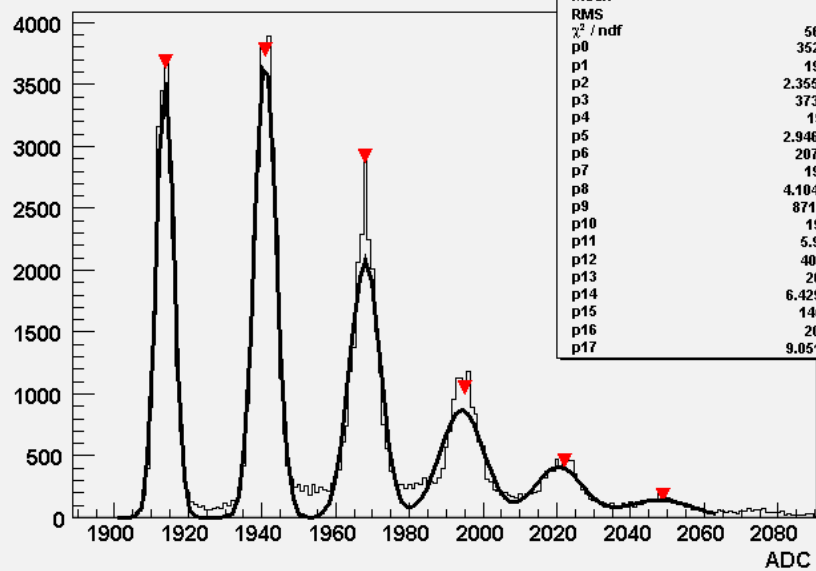


χ^2 / ndf 1.486 / 4
p0 0.4286 ± 0.7237
p1 25.83 ± 0.239

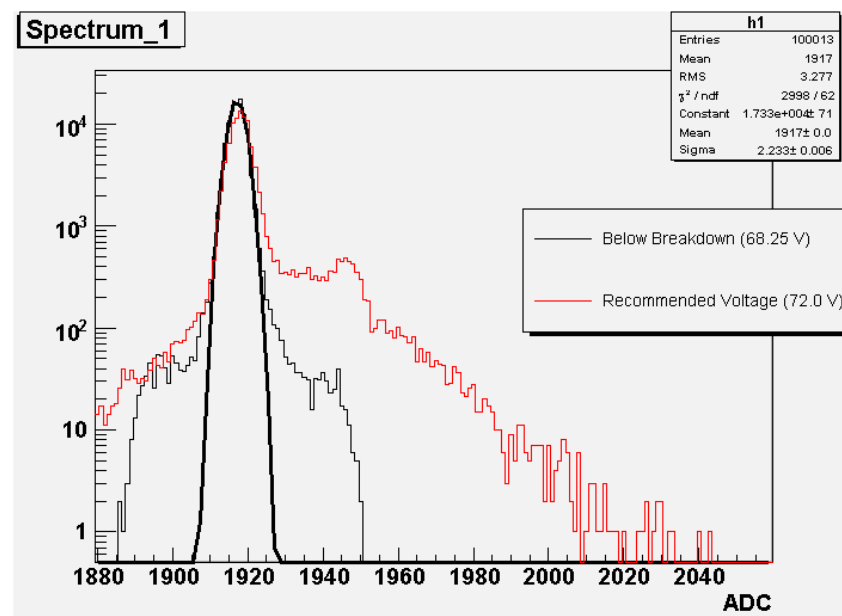
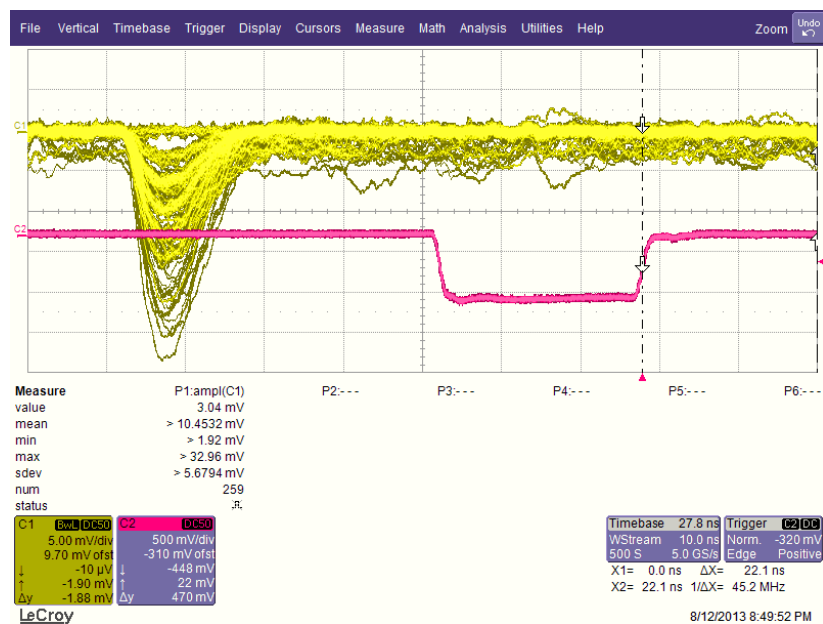
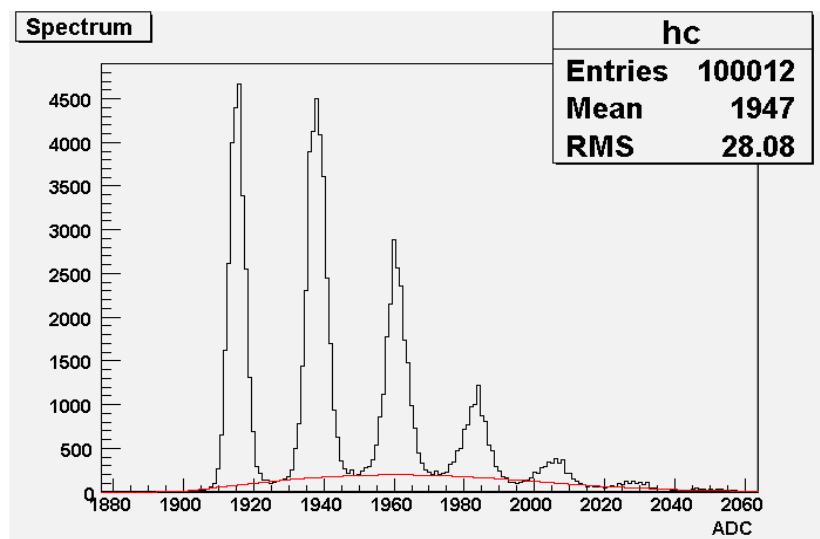
Gain vs Bias Voltage



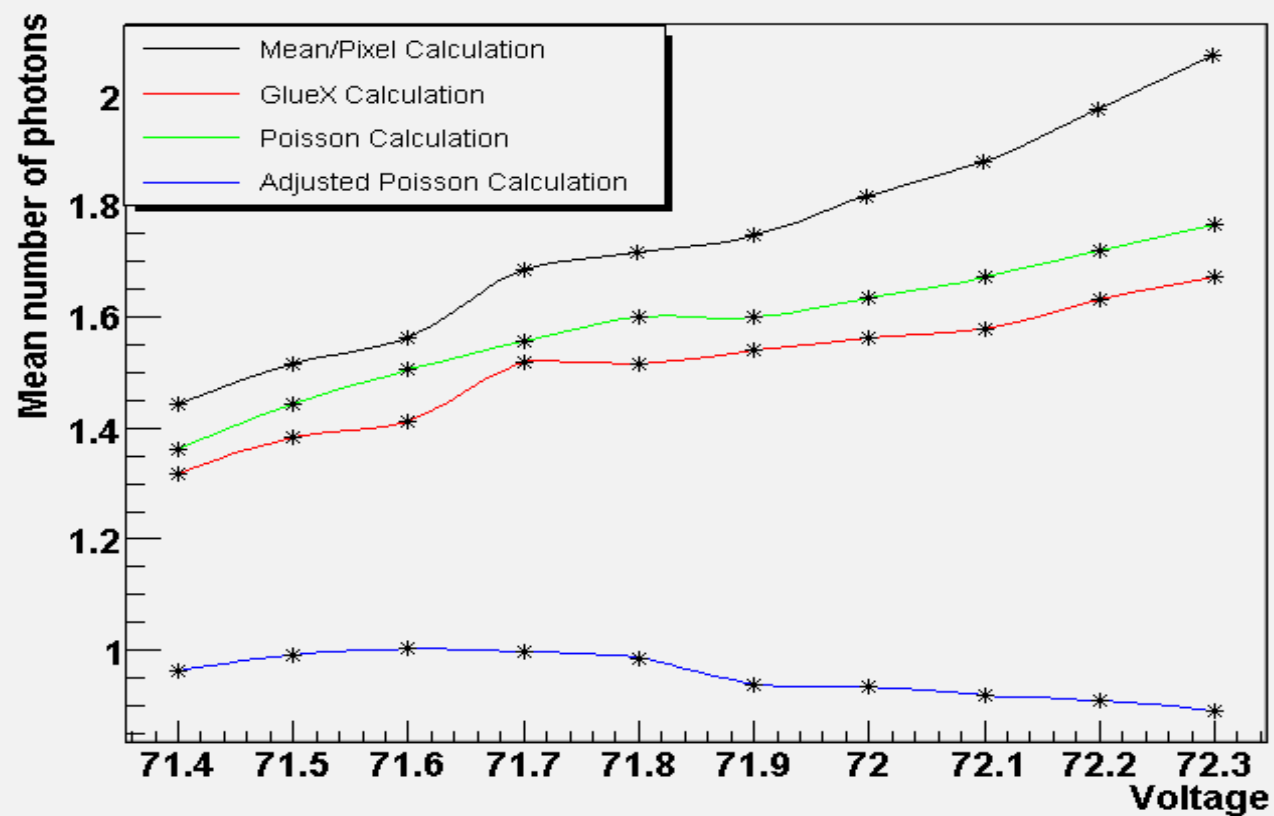
Pedestal



h	
Entries	100012
Mean	1959
RMS	37.61
χ^2 / ndf	5612 / 147
p0	3529 \pm 31.0
p1	1914 \pm 0.0
p2	2.355 \pm 0.014
p3	3736 \pm 30.3
p4	1941 \pm 0.0
p5	2.946 \pm 0.016
p6	2077 \pm 19.6
p7	1968 \pm 0.0
p8	4.104 \pm 0.030
p9	871.4 \pm 13.7
p10	1994 \pm 0.1
p11	5.98 \pm 0.09
p12	409.9 \pm 7.2
p13	2020 \pm 0.1
p14	6.429 \pm 0.131
p15	145.6 \pm 3.4
p16	2048 \pm 0.2
p17	9.051 \pm 0.260



Photon Mean Calculations



Pixel Resolution

